

Parameter	Tr1 and Tr2
$V_{CC}$	50V
$I_{C(MAX.)}$	100mA
$R_1$	22k $\Omega$
$R_2$	22k $\Omega$

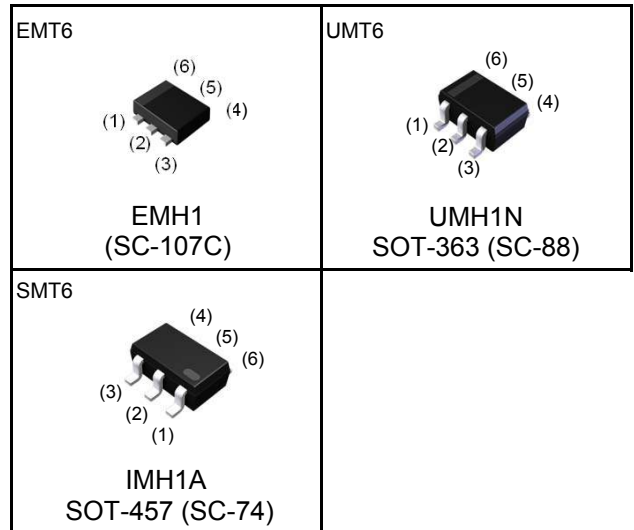
### ●Features

- 1) Built-In Biasing Resistors,  $R_1 = R_2 = 22k\Omega$ .
- 2) Two DTC124E chips in one package.
- 3) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 4) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 5) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 6) Lead Free/RoHS Compliant.

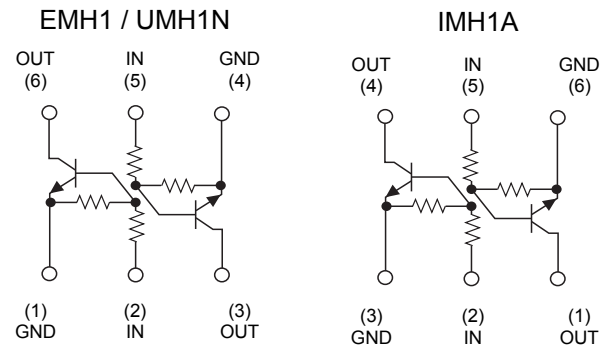
### ●Application

Inverter circuit, Interface circuit, Driver circuit

### ●Outline



### ●Inner circuit



### ●Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
EMH1	EMT6	1616	T2R	180	8	8,000	H1
UMH1N	UMT6	2021	TN	180	8	3,000	H1
IMH1A	SMT6	2928	T110	180	8	3,000	H1

●Absolute maximum ratings (Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Values	Unit	
Supply voltage	$V_{CC}$	50	V	
Input voltage	$V_{IN}$	-10 to +40	V	
Output current	$I_O$	30	mA	
Collector current	$I_{C(MAX.)}^{*1}$	100	mA	
Power dissipation	EMH1 / UMH1N	$P_D^{*2}$	150 (Total) <sup>*3</sup>	mW
	IMH1A		300 (Total) <sup>*4</sup>	mW
Junction temperature	$T_j$	150	°C	
Range of storage temperature	$T_{stg}$	-55 to +150	°C	

●Electrical characteristics (Ta = 25°C)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = 5V, I_O = 100\mu A$	-	-	0.5	V
	$V_{I(on)}$	$V_O = 0.2V, I_O = 5mA$	3.0	-	-	
Output voltage	$V_{O(on)}$	$I_O / I_I = 10mA / 0.5mA$	-	0.1	0.3	V
Input current	$I_I$	$V_I = 5V$	-	-	0.36	mA
Output current	$I_{O(off)}$	$V_{CC} = 50V, V_I = 0V$	-	-	0.5	$\mu A$
DC current gain	$G_I$	$V_O = 5V, I_O = 5mA$	56	-	-	-
Input resistance	$R_1$	-	15.4	22	28.6	k $\Omega$
Resistance ratio	$R_2/R_1$	-	0.8	1	1.2	-
Transition frequency	$f_T^{*1}$	$V_{CE} = 10V, I_E = -5mA,$ $f = 100MHz$	-	250	-	MHz

\*1 Characteristics of built-in transistor

\*2 Each terminal mounted on a reference footprint

\*3 120mW per element must not be exceeded.

\*4 200mW per element must not be exceeded.

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Input voltage vs. output current (ON characteristics)

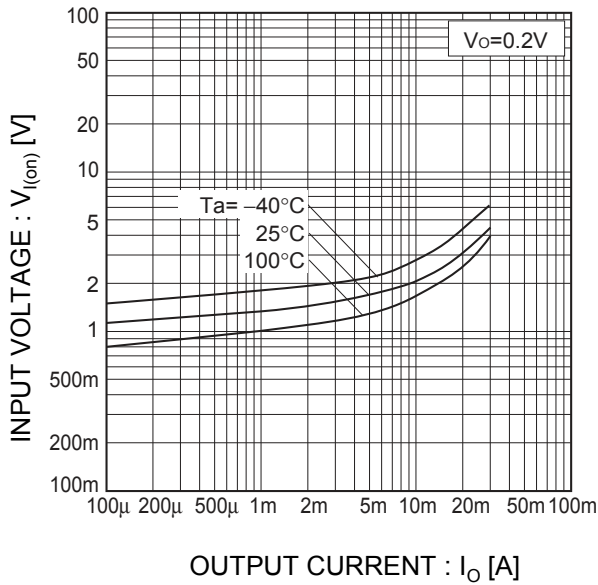


Fig.2 Output current vs. input voltage (OFF characteristics)

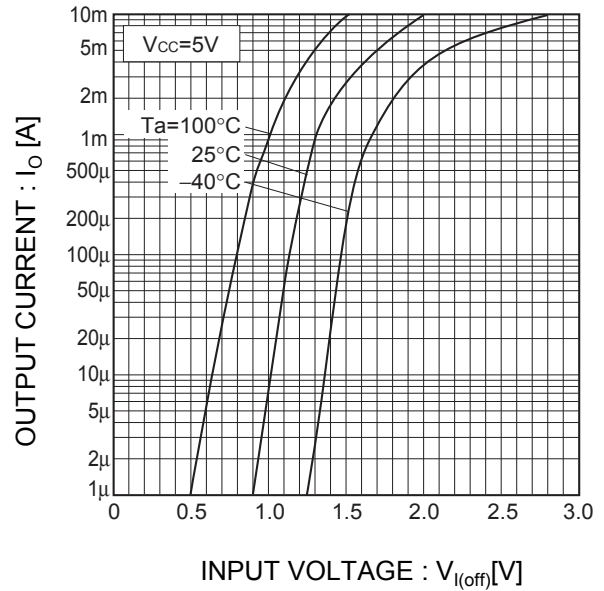


Fig.3 Output current vs. output voltage

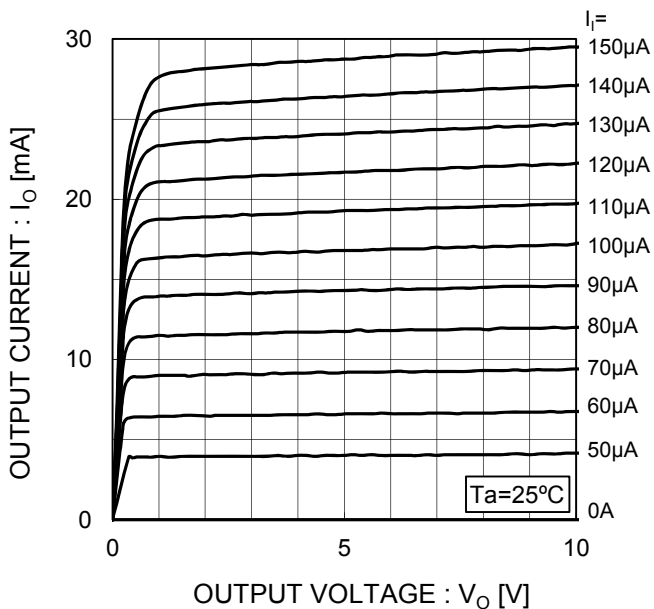
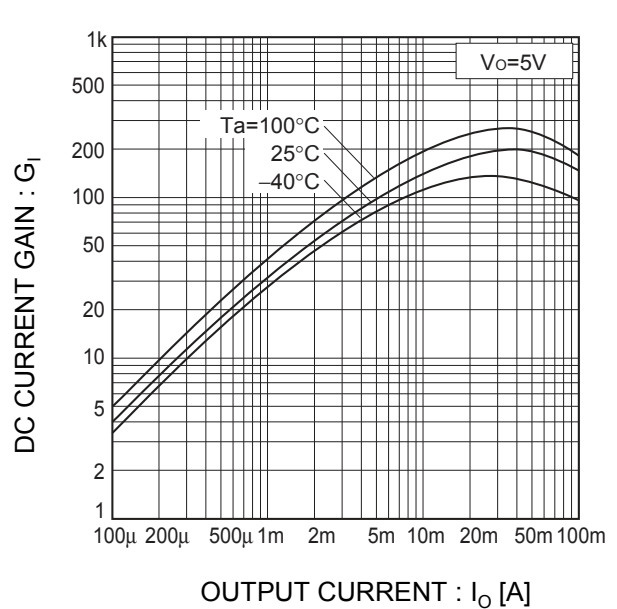
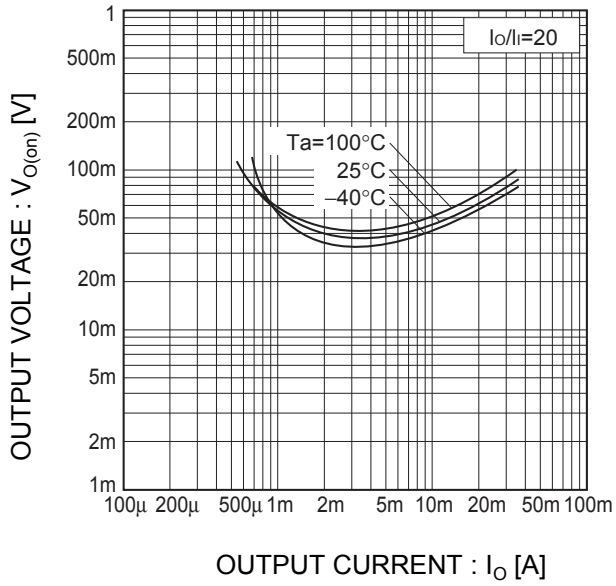


Fig.4 DC current gain vs. output current



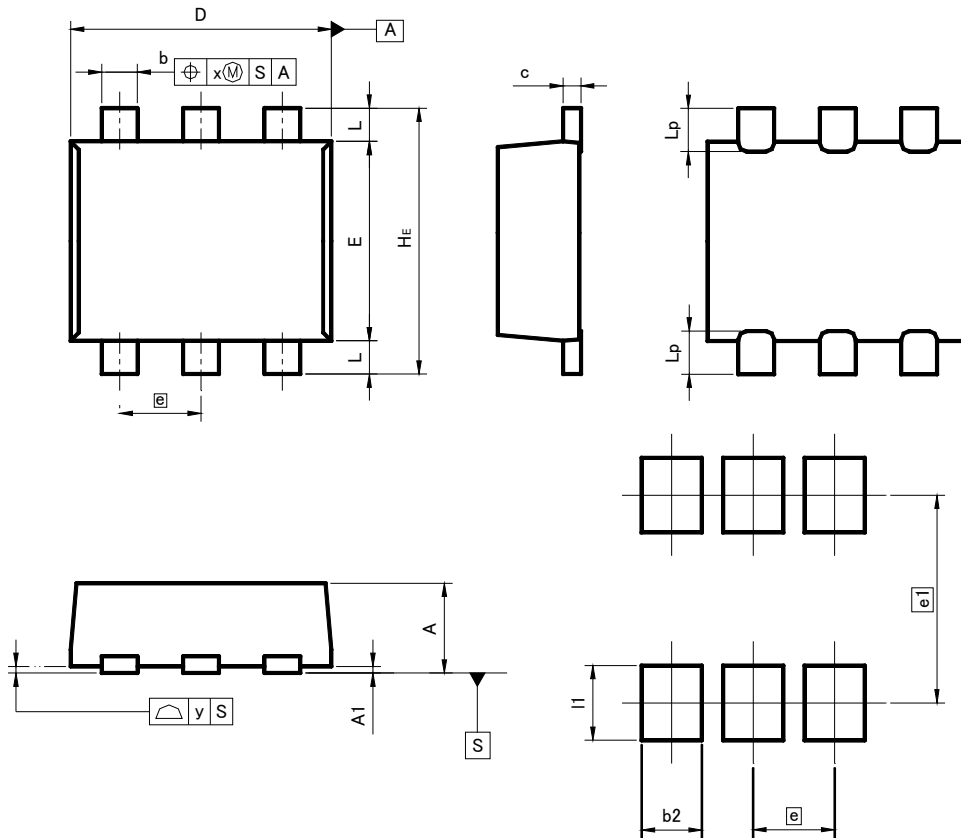
●Electrical characteristic curves(Ta = 25°C)

Fig.5 Output voltage vs. output current



●Dimensions (Unit : mm)

EMT6



Pattern of terminal position areas

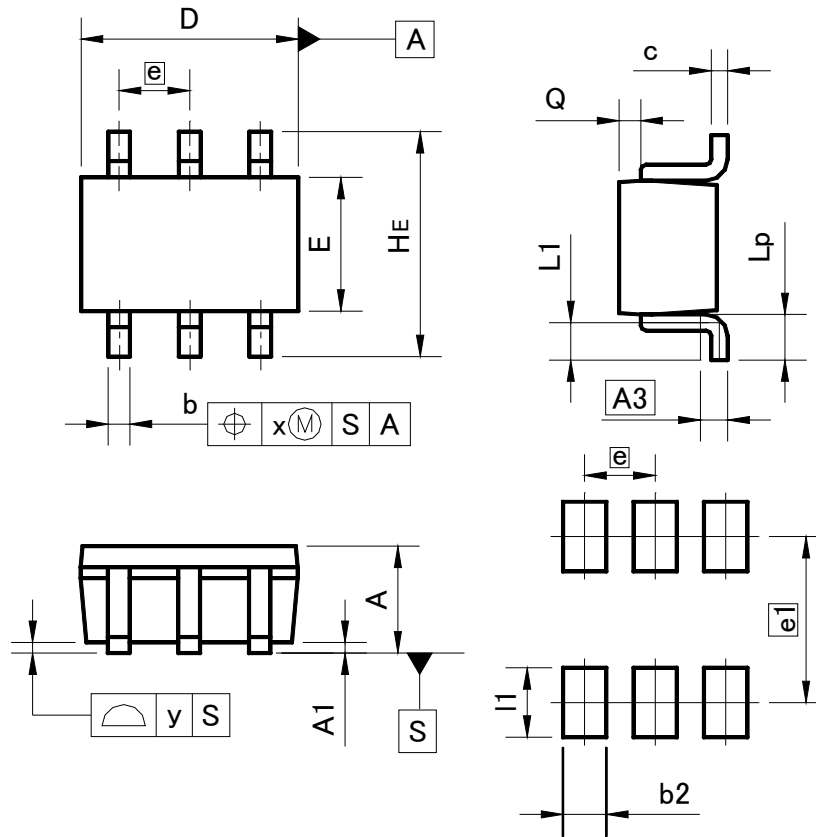
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A1	0.00	0.10	0	0.004
A	0.45	0.55	0.018	0.022
b	0.17	0.27	0.007	0.011
c	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	1.10	1.30	0.043	0.051
e	0.50		0.02	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	-	0.35	-	0.014
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	1.25		0.049	
b2	-	0.37	-	0.015
l1	-	0.45	-	0.018

Dimension in mm/inches

●Dimensions (Unit : mm)

UMT6



**Pattern of terminal position areas**

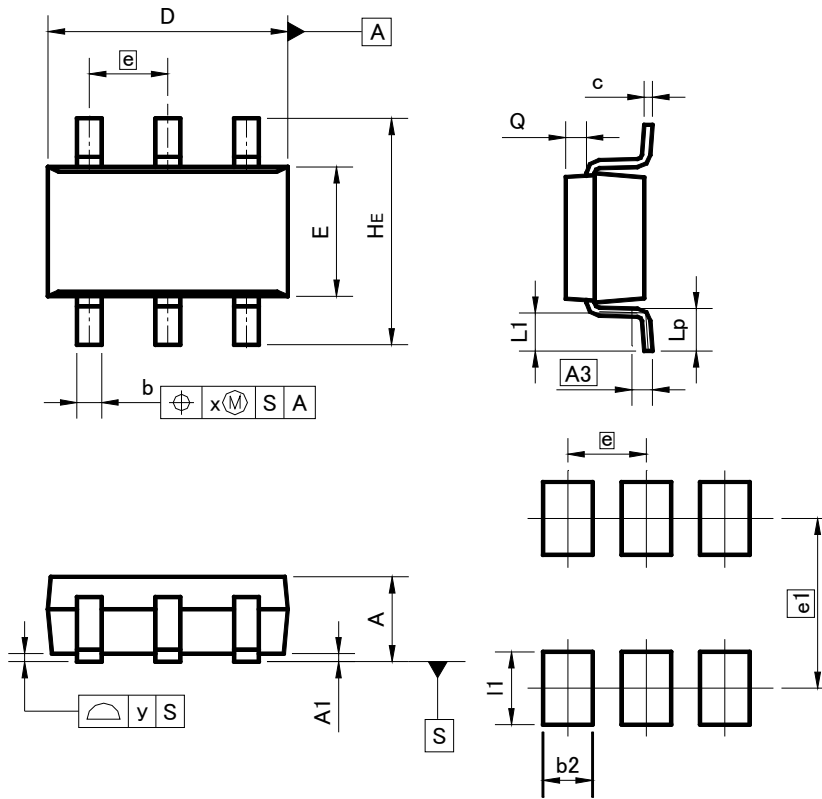
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.80	1.00	-	0.039
A1	0.00	0.10	0	0.004
A3	0.25		0.01	
b	0.15	0.30	0.006	0.012
c	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.03	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.02
Lp	0.25	0.55	0.01	0.022
Q	0.10	0.30	0.004	0.012
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	1.55		0.06	
b2	-	0.40	-	0.016
h1	-	0.65	-	0.026

Dimension in mm/inches

●Dimensions (Unit : mm)

SMT6



Pattern of terminal position areas

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.00	1.30	0.039	0.051
A1	0.00	0.10	0	0.004
A3	0.25		0.01	
b	0.25	0.40	0.01	0.016
c	0.09	0.25	0.004	0.01
D	2.80	3.00	0.11	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.04	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
x	-	0.20	-	0.008
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	2.10		0.08	
b2	-	0.60	-	0.024
I1	-	0.90	-	0.035

Dimension in mm/inches

## Notes

- 1) The information contained herein is subject to change without notice.
- 2) Before you use our Products, please contact our sales representative and verify the latest specifications :
- 3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors.  
Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Products beyond the rating specified by ROHM.
- 4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.
- 5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.
- 6) The Products are intended for use in general electronic equipment (i.e. AV/OA devices, communication, consumer systems, gaming/entertainment sets) as well as the applications indicated in this document.
- 7) The Products specified in this document are not designed to be radiation tolerant.
- 8) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative : transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.
- 9) Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
- 10) ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
- 11) ROHM has used reasonable care to ensure the accuracy of the information contained in this document. However, ROHM does not warrant that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
- 12) Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting from non-compliance with any applicable laws or regulations.
- 13) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
- 14) This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM.



Thank you for your accessing to ROHM product informations.  
More detail product informations and catalogs are available, please contact us.

## ROHM Customer Support System

<http://www.rohm.com/contact/>